Textured PDMS films applied to thin crystalline silicon solar cells

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Abstract—Front surface texturization is a standard procedure used to improve optical properties of photovoltaic devices. In some particular cases, such as when dealing with ultrathin substrates, common texturization techniques can become unpractical or even unfeasible. Texturized polymer films applied on top of such devices may be used as an alternative. In this work, we report on the development of textured PDMS films to be placed on top of planar crystalline silicon solar cells based on thin substrates (≤ 40 μm). The PDMS polymer is deposited onto a rough surface (conventional random pyramid textured silicon), cured and detached from it. By SEM images, we demonstrate that the dilution of PDMS into toluene helps in a better replica of the master surface. Next, we apply the optimized PDMS films on top of dummy samples based on 10, 20 and 40 μm-thick crystalline silicon (c-Si) substrates whose reflectance is significantly reduced after placing the PDMS films. Accurate optical simulations indicate that the optical improvement comes from three mechanisms: higher light transmission into the device, lower reflectance at the c-Si surface and better light trapping properties at the thin c-Si absorber. Experimental verification of the optical improvement with texturized PDMS films is reported based on 40 μm thick solar cell where a short-circuit current density gain of 1.7 mA/cm² is observed.

Index Terms—Thin crystalline silicon solar cells, surface texture

I. INTRODUCTION

Photovoltaic devices suffer from reflection losses at the front surface due to the high refractive index contrast between the air and the absorber. One way to reduce these losses in a wide spectrum range is through the definition of some texture patterning with two main strategies. On the one hand, structures whose size is bigger than the incident wavelength can be defined in order to scatter the incoming light and increase the probability of the photon transmission through multiple reflections. Examples for this strategy are the random upright pyramids on monocrystalline silicon substrates [1-2], the isotextured surface found in multicrystalline silicon solar cells [3-4] or the texturized surfaces for amorphous silicon solar devices [5-6]. On the other hand, nanopatterning is used to define structures smaller than the incident wavelengths creating a gradual transition of refractive indexes such as the case of black silicon surfaces [7-8]. A combination of both strategies have been also explored with promising results [9]. Such patterning strategies may not be technologically feasible. This is the case for epitaxially growth III-V solar cells or for most of thin film technologies. In such cases, a texturized transparent film could be deposited on top of the device [10-12]. These films are typically fabricated based on polydimethylsiloxane (PDMS) films that replicate a textured surface of a master [13-14].

Among all the devices where this approach can be useful, we are interested in c-Si solar cells fabricated on thin substrates (≤ 40 μm). Most common texturization methods, such as random pyramids formation by alkali etchants, typically reduce 5-10 μm in thickness on each surface. Taking advantage of this, 30-40 μm thick texturized solar cells obtained by thinning down thicker substrates can be found in the literature [15]. However, the consumption of large amounts of silicon to define the texturized surface jeopardizes the feasibility of this technique to obtain thinner substrates and reduces the interest of using thin c-Si substrates as a cost-effective approach. Possible alternatives like plasma etching [16] or the already mentioned black silicon [7-8] are more suitable techniques, but difficult to apply onto stand-alone thin c-Si substrates due to their fragility. Moreover, the introduction of texturized PDMS films avoid the possible increase in surface recombination due to the texturized c-Si surface.

In this work, we report on the development of textured PDMS films and their application to solar cell structures on thin c-Si substrates glued onto glass carriers to minimize their risk of breakage. In particular, we firstly focus on the manufacturing process of the PDMS films that leads to a better replica of the master. Next, we apply these films onto experimental samples on thin c-Si substrates to characterize them. Using optical simulations, we analyse the potential improvement in optical response focusing on light trapping properties in the thin c-Si absorbers due to the presence of texturized PDMS films. Finally, experimental verification of the optical improvement is reported.
II. EXPERIMENTAL

We used PDMS elastomer 184 Sylgard from Dow Corning as polymer. It is supplied as a 2-part liquid component kit that must be mixed in a 10:1 mass ratio. Apart from these two basic components, we add toluene in three different PDMS:toluene volume proportions of 5:1, 10:1 and 15:1. After extracting the bubbles in vacuum, we deposit the mixture onto the master surface which was previously dipped into toluene to help in the subsequent detachment of the PDMS foils. In this work, we use a random-pyramid textured c-Si substrate with pyramids in the range of 2-5 $\mu$m tall in order to benefit from both lower front reflectance and better light trapping properties. Although the obtained mixture could be cured in short times by increasing the temperature, we decided to cure it at room temperature to get a flexible elastomer that could better replicate the master surface. After 48 hours of curing, the flexible film is detached obtaining a negative replica of the master surface. Typical thickness of the PDMS film is ~160 $\mu$m.

III. RESULTS AND DISCUSSION

A. Replica quality

In figure 1, we show Scanning Electron Microscope (SEM) images of the textured PDMS surface for the three explored PDMS:toluene dilutions namely 5:1, 10:1 and 15:1. As it can be seen in the figures, the quality of the texture transfer is very dependent on the dilution used. Soft edges and defects (randomly distributed small pores) in the PDMS films can be seen for the 15:1 film over all the explored surface. These defects tend to vanish as the toluene content increases. As a consequence, 5:1 dilution sample is almost free of them suggesting that the highest toluene dilution explored in this work leads to better quality textured PDMS films. All images in figure 1 clearly show the formation of sharp deep valleys in the PDMS films which correspond to the pyramid apex of the master. The sharpness of this feature could be considered as a good indicator of the conformability of the PDMS film and, thus, the quality of the replicated surface. In the insets of figure 1, we show a detail of the pyramid apex which was revealed through Focused Ion Beam (FIB) etching for the three toluene dilutions. In these images, we can see that the 15:1 sample shows a round vertex while for the 5:1 sample much sharper feature is observed. Based on these results, we can conclude that the toluene dilution of the PDMS film helps in a more accurate replica of the master surface. For the rest of the results reported in this paper, PDMS foils were fabricated using 5:1 PDMS:toluene dilution which is the highest one explored in this work.

B. Experimental verification of improvement of optical absorption for thin c-Si substrates

Once we have developed a fabrication process that is able to replicate master surface, we apply these films to increase optical absorption of thin c-Si substrates. In particular, we use double side polished 40, 20 and 10 $\mu$m thick FZ c-Si substrates provided by Virginia Semiconductor. Due to the fragility of these substrates, a mechanical carrier is needed for proper handling and processing, especially for the thinnest ones. Our idea to fabricate a solar cell onto them is to passivate the front surface and glue them onto a highly transparent glass permitting access to the rear surface where electron and hole contacts can be defined in an Interdigitated Back-Contacted (IBC) structure [11][17]. In order to characterize the impact of the texturized PDMS films on such devices, we fabricate samples that mimic the optical configuration of the solar cell structure in a simplified way and whose cross-section can be seen in figure 2.(a).
Taking advantage that Atomic Layer Deposition technique allows an easy growth on both sides of the sample, we have identical aluminum oxide (Al₂O₃) layers on both sides of the wafer. At the front surface, this layer will be present in the final cell structure because it provides excellent surface passivation and improves optical response of the cell [18-19], while at the rear surface the Al₂O₃ layer is coated with an evaporated Aluminum film to create a back reflector. Finally, we use a transparent epoxy EpoTek 302-3M to glue the sample onto a 0.7 mm Schott Borofloat 33 glass.

Figure 2. (a) Cross-section of the samples fabricated to evaluate the optical improvement by introducing the PDMS film. Texturized PDMS films are placed on top of the glass. (b) Cross-section of the fabricated solar cells.

Figure 3 shows the reflectance ($R$) measurements with and without the PDMS film for the three sample thicknesses. As it can be seen, similarly to other reported results [14] a strong reduction of the reflectance is measured in all cases when the texturized PDMS film is introduced indicating that more light is absorbed in the c-Si substrate. In order to quantify this improvement in c-Si optical absorption, we perform optical simulations using raytracing software GenPro4 [20]. We reproduce the sample structure while optical properties of the different films (refractive index, $n$, and extinction coefficient, $k$) were obtained through different ways. For the thin Al₂O₃ films, spectroscopic ellipsometry measurements were carried out while constants for Aluminum [21] and c-Si [22] were extracted from the literature. Extinction coefficients of the epoxy, the glass and the PDMS film were experimentally determined by measuring absorbance and applying the Beer-Lambert law [23]. Finally, refractive index of epoxy and PDMS were obtained from their datasheets while for the glass we used data reported in [24]. Regarding top surface geometry of the texturized PDMS, we defined inverted pyramids using the data given by the simulator manufacturer as typical random pyramid c-Si texturization which reproduces the master surface used.

With all this information, we carried out the simulations with only one free parameter: c-Si substrate thickness. The indicated thickness values are nominal values with tolerance of ±2 μm for 10 and 20 μm thick substrates and ±4 μm for 40 μm thick ones. The substrate thickness was adjusted in the simulations inside these intervals in order to get the best fit of the experimental data. The results can be seen in figure 3 where a good agreement is obtained between experimental and simulated data indicating that optical response of texturized PDMS films are accurately modeled.

![Figure 2](image2.png)

Fig. 2. (a) Cross-section of the samples fabricated to evaluate the optical improvement by introducing the PDMS film. Texturized PDMS films are placed on top of the glass. (b) Cross-section of the fabricated solar cells.

![Figure 3](image3.png)

Fig. 3. Experimental and simulated reflectance data for the optical samples with three c-Si substrate thicknesses: (a) 10 μm, (b) 20 μm and (c) 40 μm.

C. Analysis of the origin of absorption improvement

The excellent correspondence between experiments and optical calculations allows us to get a deeper insight into the optical benefits of the texturized PDMS films when they are applied onto thin c-Si solar cells. Since we are interested in c-Si solar cells for terrestrial applications, we consider an
AM1.5g spectrum with 100 mW/cm² as our potential light source with a useful spectral range of 300 to 1200 nm. Consequently, we can summarize the dependence of optical magnitudes (absorption, transmittance or reflectance) on wavelength by a potential photogenerated current density \( J_{ph} \). To do so, we must apply AM1.5g spectrum to the corresponding magnitude, integrate over wavelength range and translate the quantity of photons to transmittance, considering that every photon generates only one electron-hole pair potentially collectable. In other words, with AM1.5g as photon flux in photons/cm² nm:

\[
J_{ph} = q \int_{300}^{1200} X(\lambda) \cdot AM1.5g \ d\lambda
\]  

where \( q \) is the fundamental charge and \( X \) is the reflectance \( (R) \), transmittance \( (T) \) or absorbance \( (A) \) of the corresponding structure under analysis. For these calculations we consider that the \( J_{ph} \) value carried by AM1.5g in the mentioned wavelength range is 46.46 mA/cm².

To accurately simulate the potential gain in \( J_{ph} \) for the finished solar cells, we introduce in the simulations the front surface structure used in such devices and shown in figure 2. (b). The main difference is the introduction of a silicon carbide \((\text{SiC})\) layer between the epoxy and the \( \text{Al}_2\text{O}_3 \) film. This combination has already been used in other solar cell structures fabricated by the group [25]. The optical parameters \( n \) and \( k \) of the SiC layers, which are similar to conventional silicon nitride films [26], are determined by spectroscopic ellipsometry measurements. Thicknesses of the layers of this stack are tuned to work as an optimum anti-reflection coating for AM1.5g, i.e. low reflection at wavelengths \(~600\text{ nm}\) where the photon flow is maximum.

The optical improvement due to the texturized PDMS films can be divided in three effects: (i) reduction of reflection at the air/glass interface; (ii) reduction of photons reflected at the \( \text{Al}_2\text{O}_3/\text{c-Si} \) interface where the contrast between refractive indexes is maximum; and (iii) the improvement of light confinement properties once the photons are transmitted into the c-Si absorber. In the following paragraphs the impact of texturized PDMS films on every mechanism is analysed.

Regarding photon reflection on the front surface, the textured surface helps in transmitting photons inside the material since the reflected photon can impinge again onto the PDMS surface of the opposite pyramid wall having a second opportunity to be transmitted. Through optical simulations we can calculate the light transmitted for both cases: a flat glass surface and a texturized PDMS. The former leads to a transmission of 96.0 % which agrees with the difference in refractive indexes \( (n_{\text{air}} = 1, \ n_{\text{glass}} = 1.5) \) while the latter increases light transmission to about ~99.8 %. The effect in the available \( J_{ph} \) shows that transmitted photons are equivalent to \( J_{ph} = 45.08 \text{ mA/cm²} \) for the flat surface while with PDMS film we obtain \( J_{ph} = 46.37 \text{ mA/cm²} \), which means an increase of 1.29 mA/cm².

The second effect deals with photons reflected at \( \text{Al}_2\text{O}_3/\text{c-Si} \) interface where the contrast of refractive index is maximum. In the optical simulator, we define a structure with the same front surface configuration, but with an infinitely thick c-Si absorber. By doing so, we can calculate the photons that are transmitted into the c-Si for both cases: with and without the texturized PDMS film on top of the glass. The results are shown in figure 4. It should be mentioned that the transmission through the front 35 nm thick \( \text{Al}_2\text{O}_3 \) layer is almost identical to the light transmitted to c-Si and it has not been included in the graph. As it can be seen, for the flat surface a significant part of photons that are reflected at the \( \text{Al}_2\text{O}_3/\text{c-Si} \) surface escape from the device increasing the total reflectance (in the graph indicated by the white area). On the other hand, the introduction of the texturized PDMS films scatters the light and part of the photons that are reflected at the \( \text{Al}_2\text{O}_3/\text{c-Si} \) interface is internally reflected again preventing them to escape from the structure and reducing optical losses. Simultaneously, the absorption of every material can be also evaluated in these graphs. The most important parasitic absorption corresponds to the epoxy that shows a strong absorption in the UV part preventing most of the photons below 350 nm to reach the c-Si surface. Moreover, the introduction of PDMS film results in some absorption in the UV and IR part.

![Fig. 4. Light transmitted through every layer following the front surface configuration of the experimental samples with (a) flat surface and (b) introducing PDMS foils. It should be mentioned that the \( \text{Al}_2\text{O}_3 \) film does not absorb any photon and its transmission data coincides with the one into c-Si.](image)

Table I shows the corresponding \( J_{ph} \) values at every layer. Despite 0.27 mA/cm² absorbed in the texturized PDMS film
and a slight increase in parasitic absorption in the glass and the epoxy, the introduction of the texturized film improves the light transmitted to the c-Si leading to an increase in \( J_{ph} \) from 39.85 mA/cm\(^2\) to 42.76 mA/cm\(^2\), which means 2.91 mA/cm\(^2\) more.

**TABLE I**

<table>
<thead>
<tr>
<th>Flat</th>
<th>Texturized PDMS</th>
</tr>
</thead>
<tbody>
<tr>
<td>Front reflection</td>
<td>6.09 mA/cm(^2)</td>
</tr>
<tr>
<td>PDMS</td>
<td>-</td>
</tr>
<tr>
<td>Glass</td>
<td>0.26 mA/cm(^2)</td>
</tr>
<tr>
<td>Epoxy</td>
<td>0.20 mA/cm(^2)</td>
</tr>
<tr>
<td>SiC</td>
<td>0.06 mA/cm(^2)</td>
</tr>
<tr>
<td>c-Si</td>
<td>39.85 mA/cm(^2)</td>
</tr>
</tbody>
</table>

Finally, we focus on the light trapping properties inside c-Si absorber which is of crucial importance in such thin c-Si substrates. In figure 5.(a) we plot the internal absorptance of c-Si, i.e. absorbed photons relative to the photons that enter the c-Si substrate, for the three substrate thicknesses explored in this work. In this case, we have defined an ideal back reflector at the rear surface in order to calculate the full potential of the light confinement properties. As it can be seen, c-Si internal absorption is improved at the IR spectrum in all cases when the texturized PDMS film is introduced confirming the enhanced light trapping properties. Notice that this magnitude neglects any reflection losses on the previous films, but depends on the range of angles of the incoming light and, therefore, on the light scattering introduced by the front texture. As a reference, we can calculate the internal absorption of the c-Si layer considering only vertical incidence of the light. With a perfect rear reflector, multiple reflections and Lambert-Beer law [23]:

\[
A(\lambda) = \frac{1-e^{2\alpha(\lambda)d}}{1-R_{int}e^{-2\alpha(\lambda)d}}
\]  

where \( \alpha(\lambda) \) is the absorption coefficient, \( d \) is the physical thickness of the absorber and \( R_{int} \) is the front internal reflectance calculated from the contrast of refractive indexes between c-Si and Al\(_2\)O\(_3\). Due to the front texturization, light is scattered and can be trapped inside the absorber lengthening its optical path. Therefore, as a figure of merit, we can define a path length enhancement factor, \( z(\lambda) \), to get the equivalent optical thickness, i.e. in equation (2) we should use \( d \cdot z(\lambda) \) instead of just \( d \). This \( z(\lambda) \) factor will give us the information of the light confinement respect to the vertical incidence and flat surfaces. Then, isolating \( z(\lambda) \) from equation (2):

\[
z(\lambda) = z(\lambda) = \frac{A - 1}{2 \alpha(\lambda)} \ln \left( \frac{A - 1}{AR_{int} - 1} \right)
\]  

The results of applying equation (3) are shown in figure 5.(b) for the three explored thicknesses with texturized PDMS foils (for flat surfaces \( z(\lambda) = 1 \) is obtained, not shown in the graph). As it can be seen, the optical length of the substrates is increased to almost a factor of 2 which is a significant improvement given the thin c-Si substrates.

To summarize the maximum improvement that could be expected in the fabricated solar cells fabricated with the structure proposed hereby, we calculate via simulations the potential \( J_{ph} \) with the front surface configuration of the solar cells and an ideal back reflector. The results are shown in Table II where a maximum increase in \( J_{ph} \) in the range of 3.44-3.90 mA/cm\(^2\) is calculated.

**TABLE II**

<table>
<thead>
<tr>
<th>Sample</th>
<th>Increment ( \Delta J_{ph} )</th>
<th>Relative ( \Delta J_{ph} )</th>
</tr>
</thead>
<tbody>
<tr>
<td>Flat</td>
<td>3.90 mA/cm(^2)</td>
<td>14.1 %</td>
</tr>
<tr>
<td>Texturized PDMS</td>
<td>3.61 mA/cm(^2)</td>
<td>12.0 %</td>
</tr>
<tr>
<td>10 ( \mu m )</td>
<td>3.44 mA/cm(^2)</td>
<td>10.7 %</td>
</tr>
<tr>
<td>20 ( \mu m )</td>
<td>3.44 mA/cm(^2)</td>
<td>10.7 %</td>
</tr>
<tr>
<td>40 ( \mu m )</td>
<td>3.44 mA/cm(^2)</td>
<td>10.7 %</td>
</tr>
</tbody>
</table>

**D. Experimental result on finished solar cells**

Finally, we have applied the texturized PDMS films onto finished IBC c-Si solar cells fabricated on 40 \( \mu m \) thick substrates. The cross-section of the fabricated devices is shown in figure 2.(b). The applied technology is similar to the one reported by our research group in reference [27] where hole contacts are based on vanadium oxide (VO\(_x\)) layers while
electron contacts are defined by laser processing phosphorus doped silicon carbide film stack (SiCₓ(n) stack). A detailed description of the fabrication process with the obtained results will be published elsewhere. Focusing on the work reported hereby, 1x1 cm² solar cells are measured under standard conditions (AM1.5g, 100 mW/cm², 25 °C) leading to an increase of short-circuit current density (Jₛccoli) from 26.7 mA/cm² to 28.4 mA/cm² when texturized PDMS films are placed on top of the glass. Despite the improvement of 1.7 mA/cm² in Jₛccoli is far from the maximum potential obtainable from the simulations, it clearly demonstrates the benefits of the texturized PDMS films. It must be mentioned that the simulated Jₛccoli values are the maximum potential Jₛccoli that could be obtained in a final device without any recombination and ideal back reflector. Then, the suboptimal rear optical structure of the real device and the inherent recombination processes at the bulk and surfaces (in particular at the front) could perfectly explain the deviation from the ideal case.

In order to get a deeper insight of the origin of this improvement, in figure 6 we show External Quantum Efficiency (EQE) of the best cell with (EQEₚdms) and without (EQEₕlat) texturized PDMS film. Additionally, the ratio between these two magnitudes is also plotted on the left axis. A clear increase in EQE is observed when the texturized PDMS film is introduced, in particular at the IR part of the spectrum.

![EQE graph](image)

**Fig. 6.** External Quantum Efficiency measurements of 40 μm-thick finished solar cells with and without texturized PDMS. The ratio between these two magnitudes is also plotted on the left axis. A clear increase in EQE is observed when the texturized PDMS film is introduced, in particular at the IR part of the spectrum.**

The authors would like to thank Dr. E. Johnson from LPICM for his support in the spectroscopic ellipsometry measurements.

**REFERENCES**


